

**CRYSTAL STRUCTURE OF NEW PHASES IN THE Zr–Ru–Ga SYSTEM
IN THE REGION OF HIGH Ga CONTENT**

*Shatalov B. S.*¹, Babizhetskyy V. S.¹, Myakush O. R.², Kotur B. Ya.¹

¹Department of Inorganic Chemistry, Ivan Franko National University of Lviv, Kyryla & Mefodia Str. 6, 79005, Lviv, Ukraine

²National University of Forest and Wood Technology of Ukraine, Chuprynyk Str., 103, 79057 Lviv, Ukraine

bohdan.shatalov@lnu.edu.ua

The Zr–Ru–Ga system has been partially studied in the region of 0–50 at. % Ga in [1–3], which revealed the existence of two ternary compounds with the MgZn₂-type structure (space group (SG) *P6₃/mmc*): ZrRu_xGa_{2-x} (0.60 < *x* < 0.96), *a* = 5.2475(5) – 5.2557(1), *c* = 8.3923(7) – 8.2854(1) Å [1] and Zr_{1-x}Ga_xRu₂ (*x* = 0.18), *a* = 5.1399(1), *c* = 8, 4888(2) Å [2], and solid solutions based on binary RuGa and ZrRu compounds with the CsCl-type structure (SG *Pm-3m*) [3]. In this work the Zr–Ru–Ga system was investigated in the region of high Ga content (>50 at. %) at 870 K.

The samples for the study were prepared by melting a charge of compact high-purity metals in an electric arc furnace under a purified argon atmosphere. The heat treatment of the alloys consisted of homogenizing annealing at 870 K for 720 hours. Phase analysis of the alloys was performed using an array of powder X-ray diffraction data (XRD) obtained using DRON-2.0M (FeK_α radiation) and STOE STADI P (CuK_{α1} radiation) powder diffractometers. The energy dispersive X-ray spectroscopy (EDX) was used to confirm the atomic ratio of elements in each phase. Single crystal data for Zr₇Ru₆Ga₁₇ were collected at room temperature on a Bruker D8 Venture diffractometer with monochromatized MoK_α radiation.

In the studied concentration range, the existence of the ternary compound Zr₇Ru_{6+x}Ga_{17-x} (0 ≤ *x* ≤ 2.0) and solid solutions of substitution based on binary compounds RuZr_xGa_{2-x} (0 < *x* < 0, 32, ST TiSi₂, SG *Fddd*, *a* = 4.749 – 4.7501(7), *b* = 8.184 – 8.195(1), *c* = 8.696 – 8.708(2) Å), ZrRu_xGa_{3-x} (0 < *x* < 0.33, ST ZrAl₃, SG *I4/mmm*, *a* = 3.960–3.9640(4), *c* = 8.72 – 8.741(3) Å) was established. The limiting solubility of the third component in binary intermetallics was confirmed by EDX and XRD analyses.

The crystal structure of the galide Zr₇Ru₆Ga₁₇ was investigated by the single-crystal method. The compound Zr₇Ru₆Ga₁₇ crystallizes in a new structure type (Pearson's symbol *cF120*, space group *Fm-3m*, *a* = 12.409(1) Å, *Z* = 4, *R*₁ = 0.037, *wR*₂ = 0.091 for 172 independent reflexes with *I*_o > 2σ(*I*_o) and 19 refined parameters). An decrease of the unit cell parameters indicates homogeneity range of Zr₇Ru_{6+x}Ga_{17-x} (0 ≤ *x* ≤ 2.0) for the compound at 870 K along the isoconcentrate of 23.3 at. % Zr. It is a solid solution of substitution of Ru for Ga with the limits from 50.0 to 56.7 at. % Ga.

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2. Babizhetskyy V., Myakush O., Shatalov B., Kotur B. Crystalline structure of the gallium-stabilized Laves phase Zr_{1-x}Ga_xRu₂ (*x* = 0,18) // Visnyk Lviv. Univ. Ser. Chem. 2025 (to be published).

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